## §18. Ionoluminescence of a Thin Rear-earth Oxide Film by Slow Highly-charged Ions

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i) Introduction Slow highly charged ions (HCIs) impinging on solid targets deposit its large potential energies on local areas of target surfaces, which results in enhanced emission of secondary particles and photons. Tona *et al.*<sup>1)</sup> observed strongly enhanced ionoluminescence of a thin organic-dye film by bombardment of highly-charged iodine ions with L-shell vacancies.

Recently, optical transitions useful to evaluate radiation damages in  $\text{Er}_2\text{O}_3$  coatings are being searched for advanced nuclear fusion materials research<sup>2</sup>). In a visible range, a potentially useful luminescence band due to  $4f^{11} {}^4\text{F}_{9/2} - {}^4\text{I}_{15/2}$  transition of  $\text{Er}^{3+}$  cations has been observed at 640-690 nm by electron and singly-charged ion bombardments <sup>2, 3</sup>). In the present work<sup>4</sup>), photon emission induced by HCI-beams has been investigated with the thin  $\text{Er}_2\text{O}_3$  film.

Experiment Target samples are thin polycrysii) talline  $Er_2O_3$  films of about 500 - 600 nm thickness coated on stainless steel substrates by using Metal Organic Chemical Vapor Deposition (MOCVD)<sup>5)</sup>. Kobe Electron Beam Ion Source  $(Kobe-EBIS)^{6}$  was used to produce intense HCI-beams (e. g.  $Ar^{12+}$  ion-beams of a few hundreds pA in current for acceleration voltages of 3 kV). A LN-cooled CCD camera (VersArray 1300F) is used to detect an induced photon emission. Quantum efficiency (QE) of the CCD camera has a broad peak centered around 700 nm (QE distributes in a wavelength rage of 400 - 1100 nm). An optical filter (YIF-BA600-690S) is used to limit photon detection in a wavelength range of 607-680 nm where the strong ionoluminescence due to the  ${}^{4}F_{9/2}$  -  ${}^{4}I_{15/2}$  transition by  $Er^{3+}$  cations is anticipated<sup>2, 3</sup>).

iii) **Results and discussion** Figure 1 shows chargestate (q) dependence of detected photon counts of  $Ar^{q+}$ HCI induced emission from the  $Er_2O_3$  film. Photon emission increases rapidly along the charge state (potential energy) of projectile ions. Kinetic energies of ions also change along the charge state, because a constant acceleration voltage of 3 kV was used for all the charge states. In Fig. 2, the photon emission intensity is plotted as a function of kinetic energy of the HCIs along with electronic stopping cross sections of  $Ar^+$  ions on  $Er_2O_3$  used in the TRIM code. It is clearly seen in the figure that the induced photon emission increases more rapidly than expected by the electronic stopping of Ar<sup>+</sup>. This suggests a potential energy effect of the HCIs in the photon emission.

Some of the photon emission can also be ascribed

to line emission of sputtered neutral Er atoms which falls into a band width of the optical filter used in the present measurement. Further investigation will, therefore, be made using another optical filter of a narrower band width to separate the ionoluminescence of the oxide cations from the line emission of the sputtered neutrals.

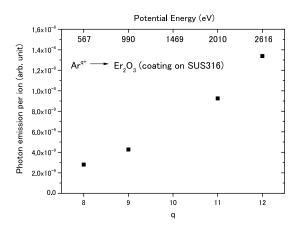


Fig. 1: Charge-state dependence of photon emission induce by  $Ar^{q+}$  HCI-beams on an  $Er_2O_3$  film.

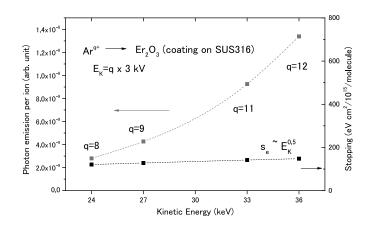


Fig. 2: Kinetic energy dependence of photon emission intensity induced by  $Ar^{q+}$  HCI-beams on an  $Er_2O_3$  film.

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